

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	27	"5552338" "6456186" "6583977"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/15 13:29
S1	13	(@ad<"20020408" or @rlad<"20020408") and (serpentine adj gate) and (source or drain or transistor) and (RC)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/14 12:41
S2	36	(@ad<"20020408" or @rlad<"20020408") and (serpentine adj gate) and (source or drain or transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/13 10:11
S3	1	(@ad<"20020408" or @rlad<"20020408") and (serpentine adj diffusion) and (source or drain or transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/13 10:12
S4	67	(@ad<"20020408" or @rlad<"20020408") and (serpentine adj resistor) and (source or drain or transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/13 10:50
S5	2263	(@ad<"20020408" or @rlad<"20020408") and (serpentine with (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon)) and (source or drain or transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/13 14:17
S7	794	(@ad<"20020408" or @rlad<"20020408") and 257/364, 360.ccls. and (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon or serpentine) and (source or drain or transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/14 13:13
S9	2602	(@ad<"20020408" or @rlad<"20020408") and (delay adj stage) and (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon or serpentine) and (source or drain or transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/14 10:50

## EAST Search History

S10	643	(@ad<"20020408" or @rlad<"20020408") and (delay adj stage) and (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon or serpentine) and (source or drain or transistor) and diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/14 11:04
S13	1702	(@ad<"20020408" or @rlad<"20020408") and (delay) and (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon or serpentine) and (capacitance near3 diode) and (source or drain or transistor) and diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/14 11:08
S14	208	(@ad<"20020408" or @rlad<"20020408") and (delay) and (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon or serpentine) and (capacitance near3 diode) and (source or drain or transistor) and diode and "257".clas.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/14 11:08
S15	5	(@ad<"20020408" or @rlad<"20020408") and (diode with (add adj capacitance)) and (source or drain or transistor) and (RC)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/14 12:44
S16	13	(@ad<"20020408" or @rlad<"20020408") and (diode with (add adj capacitance)) and (source or drain or transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/14 12:44
S17	26	("4939616"   "5012317"   "5225702"   "5453384"   "5465189"   "5502328"   "5519242"   "5581104"   "5629544"   "5631793"   "5646808"   "5654862"   "5719737"   "5754381"   "5807791"   "5811857"   "5907462"   "5910874"   "5923067"   "5932918"   "5940258"   "5990520"   "6015992"   "6034397"   "6081002"   "6218895").PN. OR ("6690065"). URPN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/03/14 13:07

## EAST Search History

S18	387	(@ad<"20020408" or @rlad<"20020408") and 257/364, 360.ccls. and (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon or serpentine) and (source or drain or transistor) and diode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/15 10:28
S19	6	(@ad<"20020408" or @rlad<"20020408") and 257/364, 360.ccls. and (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon or serpentine) and (source or drain or transistor) and diode and "thin film resistor"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/15 10:36
S20	784	(@ad<"20020408" or @rlad<"20020408") and (diffusion or resistor or polysilicon or gate or source or drain or structure or silicon or serpentine) and (source or drain or transistor) and diode and "thin film resistor"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/15 10:36